NSN 5961-01-198-0089

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View Online at https://aerobasegroup.com/nsn/5961-01-198-0089 **Inclosure Material:** Plastic **Overall Length:** Between 1.095 inches and 1.182 inches **Overall Height:** Between 0.160 inches and 0.190 inches **Overall Width:** Between 0.380 inches and 0.405 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Mounting Method:** Unthreaded hole **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 800.0 collector-to-emitter, substaining voltage, base open-circuited and 1400.0 collector-to-emitter, with voltage between base and emitter and 8.0 emitter to base voltage, dc **Current Rating Per Characteristic:** 2.50 amperes source cutoff current and 2.00 amperes source cutoff current **Power Rating Per Characteristic:** 65.0 watts small-signal input power, common-collector **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Terminal Type And Quantity:** 3 pin Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: